NSN 5961-01-370-2827

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-370-2827 **Inclosure Material:** Ceramic **Overall Length:** 0.785 inches **Overall Height:** 0.200 inches **Overall Width:** 0.310 inches **End Application:** Flight control **Component Name And Quantity:** 4 transistor **Mounting Method: Terminal Semiconductor Material:** Silicon all transistor **Voltage Rating In Volts Per Characteristic:** 100.0 drain to source voltage all transistor **Power Rating Per Characteristic:** 1.4 watts total power dissipation all transistor **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Nuclear Hardness Critical Feature:** Hardened **Test Data Document:** 88818-a532a315 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 14 printed circuit Shelf Life: N/a **Unit Of Measure: Demilitarization:** Yes - demil/mli

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